Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-221-8229

## **Inclosure Material:**

Metal

**Overall Length:** 

1.573 inches

# **Overall Height:**

0.450 inches

# **Overall Width:**

1.050 inches

## **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-3

Electrode Internally-electrically Connected To Case:

Collector

#### Mounting Method:

Unthreaded hole

# Features Provided:

Hermetically sealed case

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

850.0 collector-to-emitter substaining voltage, with voltage between base and emitter and 850.0 collector to base voltage/static/emitter open and 9.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

Between 10.00 amperes source cutoff current blank and 5.00 amperes source cutoff current and 5.00 amperes source cutoff current

# Power Rating Per Characteristic:

100.0 watts small-signal input power, common-collector absolute

#### **Transfer Ratio:**

12.0 static forward current transfer ratio, common-emitter and 60.0 static forward current transfer ratio, common-emitter

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

2 pin and 1 case

#### Shelf Life:

N/a

## Unit Of Measure:

---

## Demilitarization:

Yes - demil/mli

# **NSN 5961-01-221-8229** Transistor - Page 2 of 2

Fiig: A110a0

